

## Electronic Supplementary Information

### Improving Photovoltaic Performance of Ladder-type Dithienonaphthalene Containing Copolymers through Structural Isomerization

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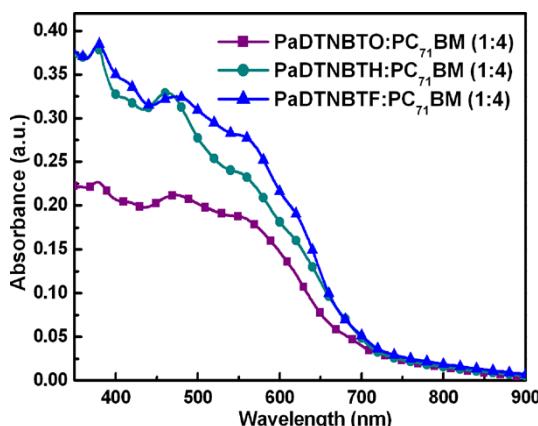


Fig. S1 Optical absorption spectra of the polymer: PC<sub>71</sub>BM blends.

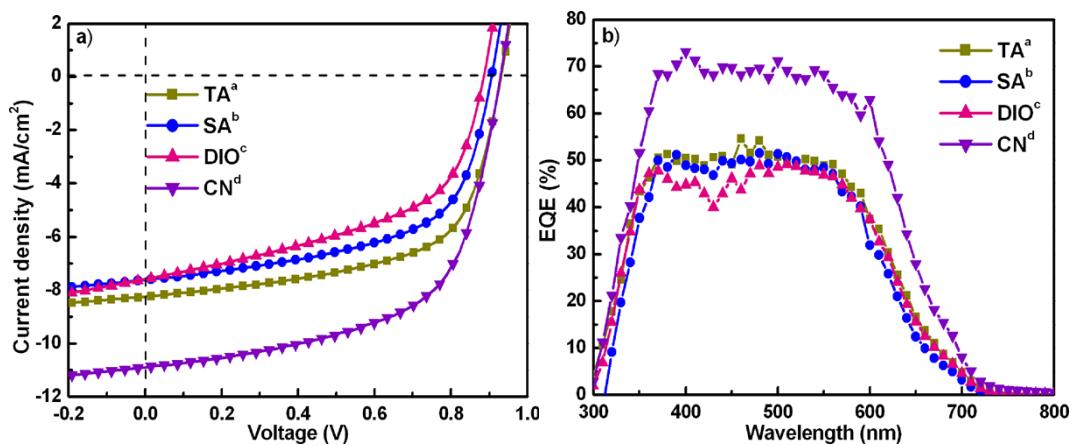
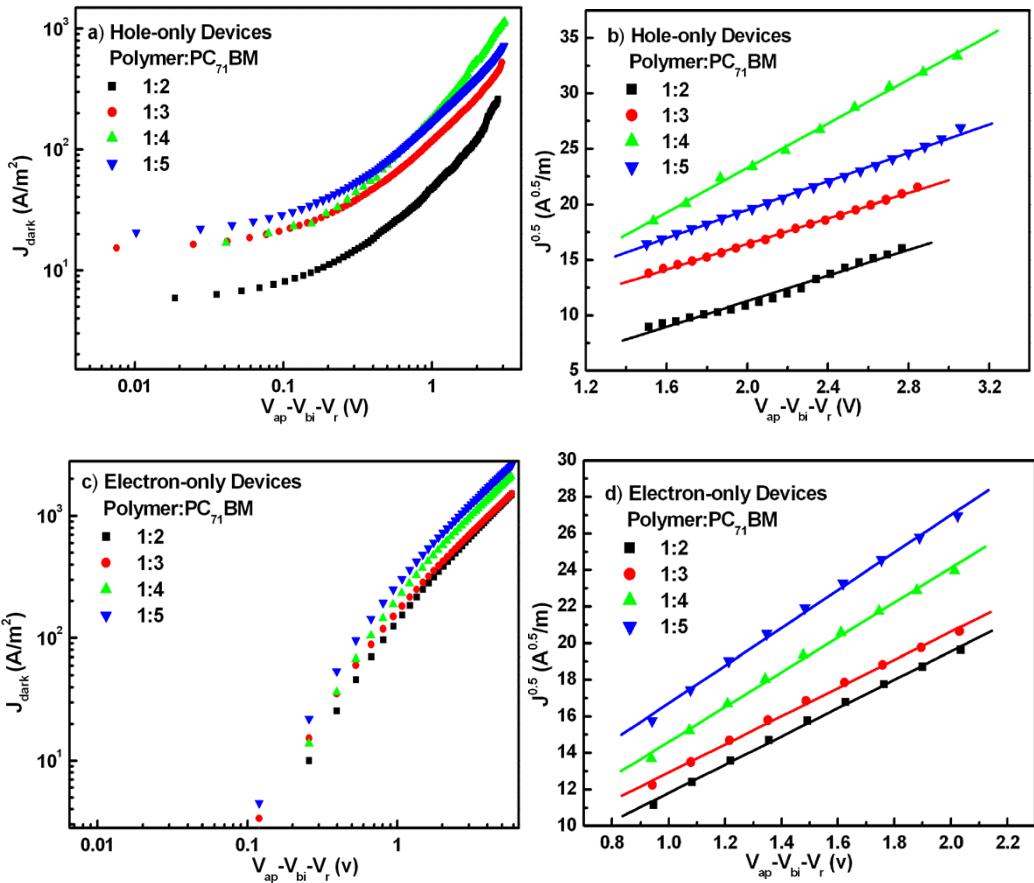
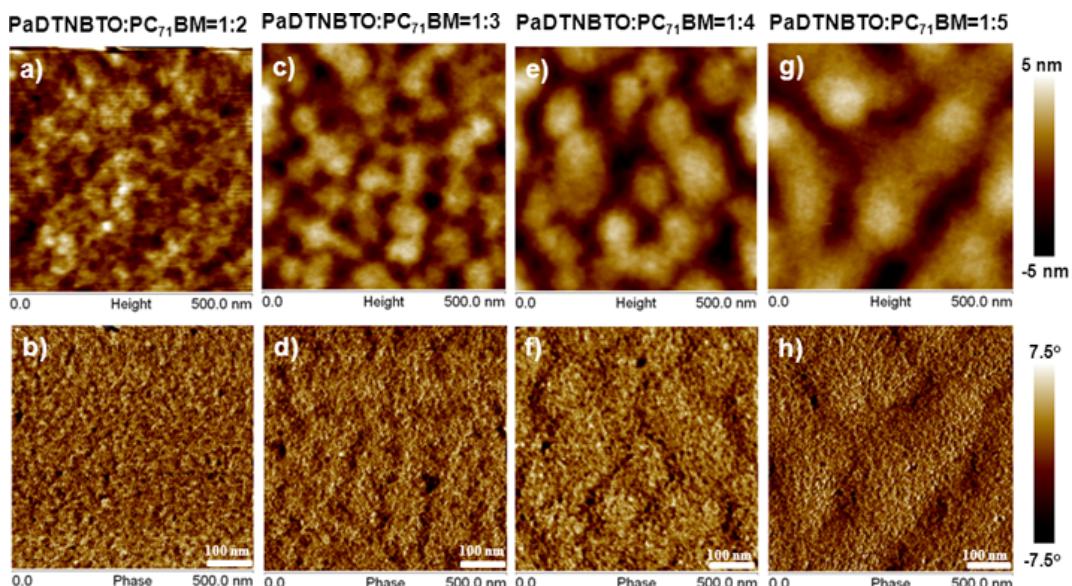


Fig. S2 (a)  $J-V$  characteristics and b) EQE curves of PSCs based on PaDTNBTO:PC<sub>71</sub>BM under different experiment conditions. <sup>a</sup>Thermal treatment (TA) at 70 °C for 5 min. <sup>b</sup>Solvent annealing (SA) with saturated *o*-dichlorobenzene vapor for 10 min. <sup>c</sup>0.3% 1, 8-octanedithiol (DIO) as an additive (v/v). <sup>d</sup>0.3% chloro-naphthalene (CN) as an additive (v/v).



**Fig. S3** (a, c)  $J$ - $V$  characteristics, and (b, d)  $J^{0.5}$ - $V$  characteristics of PaDTNBTO-based hole- and electron-only devices with different D-A ratios.



**Fig. S4** AFM topography (top) and phase (bottom) images of the blend films of PaDTNBTO and PC<sub>71</sub>BM with different D/A ratios: a,b) 1:2, c,d) 1:3, e,f) 1:4, g,h) 1:5. The size of the images is 0.5 μm × 0.5 μm.

**Table S1.** The hole mobility of hole-only devices based on different polymer

Polymer	Polymer:PC <sub>71</sub> BM	Thickness (nm)	Hole mobility (cm <sup>2</sup> ·V <sup>-1</sup> ·s <sup>-1</sup> )
PaDTNBTO	1:4	90	2.81×10 <sup>-5</sup>
PaDTNBTH	1:4	100	3.69 ×10 <sup>-5</sup>
PaDTNBTF	1:4	70	7.50×10 <sup>-6</sup>

**Table S2.** The electron and hole mobilities of PaDTNBTO:PC<sub>71</sub>BM blends with different D-A ratios

Polymer:PC <sub>71</sub> BM	Electron mobility $\mu_e$ (cm <sup>2</sup> V <sup>-1</sup> s <sup>-1</sup> )	Hole mobility $\mu_h$ (cm <sup>2</sup> V <sup>-1</sup> s <sup>-1</sup> )	$\mu_e / \mu_h$
1:2	3.30×10 <sup>-5</sup>	7.12×10 <sup>-6</sup>	4.63
1:3	3.59×10 <sup>-5</sup>	1.10×10 <sup>-5</sup>	3.26
1:4	5.26×10 <sup>-5</sup>	2.81×10 <sup>-5</sup>	1.87
1:5	6.38×10 <sup>-5</sup>	2.12×10 <sup>-5</sup>	3.00

**Table S3.** Device parameters of PSCs based on PaDTNBTO under different experiment conditions

Polymer:PC <sub>71</sub> BM	$V_{oc}$ (V)	$J_{sc}$ (mA/cm <sup>2</sup> )	FF (%)	PCE <sub>max</sub> (PCE <sub>ave</sub> <sup>a</sup> ) (%)
1:4 <sup>a</sup>	0.93	8.22	61.6	4.71 (4.41)
1:4 <sup>b</sup>	0.92	7.23	57.5	4.07 (3.98)
1:4 <sup>c</sup>	0.88	7.58	51.5	3.46 (3.27)
1:4 <sup>d</sup>	0.93	10.88	60.1	6.06 (5.91)

<sup>a</sup> Thermal annealing (TA) at 70 °C for 5 min. <sup>b</sup>Solvent annealing (SA) with saturated *o*-dichorobenzene vapor for 10 min. <sup>c</sup>0.3%1, 8-octanedithiol (DIO) as an additive (v/v). <sup>d</sup>0.3% chloronaphthalene (CN) as an additive (v/v).